

FAST CMOS OCTAL BUFFER/LINE DRIVER

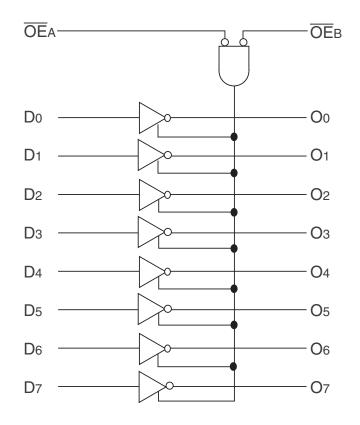
FEATURES:

- A and C grades
- Low input and output leakage ≤1µA (max.)
- CMOS power levels
- True TTL input and output compatibility:
 - VOH = 3.3V (typ.)
 - VOL = 0.3V(typ.)
- High Drive outputs (-15mA IOH, 64mA IOL)
- Meets or exceeds JEDEC standard 18 specifications
- · Power off disable outputs permit "live insertion"
- · Available in SOIC and QSOP packages

DESCRIPTION:

The IDT octal buffer/line driver is built using an advanced dual metal CMOS technology. The FCT540T is similar in function to the FCT240T, except that the inputs and outputs are on opposite sides of the package. This pinout arrangement makes these devices especially useful as output ports for microprocessors and as backplane drivers, allowing ease of layout and greater board density.

FUNCTIONAL BLOCK DIAGRAM

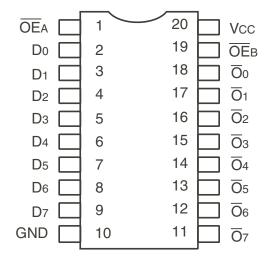


INDUSTRIAL TEMPERATURE RANGE



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PINCONFIGURATION



TOP VIEW

Package Type	Package Code	Order Code
QSOP	PCG20	QG
SOIC	PSG20	SOG

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-60 to +120	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.

2. Inputs and Vcc terminals only.

3. Output and I/O terminals only.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	10	pF
Соит	Output Capacitance	Vout = 0V	8	12	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PINDESCRIPTION

Pin Names	Description
$\overline{OE}A, \overline{OE}B$	3-State Output Enable Inputs (Active LOW)
Dx	Inputs
Ōx	Outputs

FUNCTION TABLE⁽¹⁾

	Inputs		
ŌĒA	OE B	D	Outputs
L	L	L	Н
L	L	Н	L
Н	Н	Х	Z

NOTE:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

Z = High Impedance



Feb.11.20



DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = $5.0V \pm 5\%$

Symbol	Parameter	Tes	Test Conditions ⁽¹⁾		Тур. ⁽²⁾	Max.	Unit
Vih	Input HIGH Level	Guaranteed Logic HIGH	Level	2	_	_	V
Vil	Input LOW Level	Guaranteed Logic LOW L	evel	_	_	0.8	V
Ін	Input HIGH Current ⁽⁴⁾	Vcc = Max.	VI = 2.7V	_	_	±1	μA
lil	Input LOW Current ⁽⁴⁾	Vcc = Max.	VI = 0.5V	_	_	±1	μA
Іоzн	High Impedance Output Current ⁽⁴⁾	Vcc = Max.	VI = 2.7V	_	_	±1	μA
Iozl	(3-State Output pins) ⁽⁴⁾		VI = 0.5V	_	_	±1	
li	Input HIGH Current ⁽⁴⁾	Vcc = Max., VI = Vcc (N	Vcc = Max., VI = Vcc (Max.)		_	±1	μA
Vik	Clamp Diode Voltage	VCC = Min., IIN = -18mA	Vcc = Min., IIN = -18mA		-0.7	-1.2	V
Vн	Input Hysteresis	_		_	200	_	mV
lcc	Quiescent Power Supply Current	Vcc = Max. VIN = GND or Vcc			0.01	1	mA

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
Vон	Output HIGH Voltage	Vcc = Min	Iон = –8mA	2.4	3.3	—	V
		VIN = VIH or VIL	Iон = –15mA	2	3	_	
Vol	Output LOW Voltage	Vcc = Min	IoL = 64mA	—	0.3	0.55	V
		VIN = VIH OF VIL					
los	Short Circuit Current	VCC = Max., VO = GND ⁽³⁾		-60	-120	-225	mA

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.

4. The test limit for this parameter is $\pm 5\mu A$ at TA = $-55^{\circ}C$.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditi	ons ⁽¹⁾	Min.	Тур. ⁽²⁾	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	VCC = Max. $VIN = 3.4V^{(3)}$		_	0.5	2	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open OEA = OEB = GND One Input Toggling	VIN = VCC VIN = GND	_	0.15	0.25	mA/ MHz
		50% Duty Cycle					
IC	Total Power Supply Current ⁽⁶⁾	Vcc = Max. Outputs Open fi = 10MHz	Vin = Vcc Vin = GND	_	1.5	3.5	mA
		50% Duty Cycle $\overline{OE}A = \overline{OE}B = GND$ One Bit Toggling	VIN = 3.4V VIN = GND	—	1.8	4.5	
		Vcc = Max. Outputs Open fi = 2.5MHz	VIN = VCC VIN = GND	—	3	6(5)	mA
		50% Duty Cycle OEA = OEB = GND Four Bits Toggling	Vin = 3.4V Vin = GND	_	5	14(5)	

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of Δ Icc formula. These limits are guaranteed but not tested.

6. IC = IQUIESCENT + INPUTS + IDYNAMIC

 $IC = ICC + \Delta ICC DHNT + ICCD (fiNi)$

- Icc = Quiescent Current
- Δlcc = Power Supply Current for a TTL High Input (ViN = 3.4V) DH = Duty Cycle for TTL Inputs High
- NT = Number of TTL Inputs at DH
- ICCD = Dynamic Current caused by an Input Transition Pair (HLH or LHL)
- fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)
- fi = Output Frequency
- Ni = Number of Outputs at fo

All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

			FCT540AT		FCT540CT		
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 50pF	1.5	4.8	1.5	4.3	ns
t PHL	Dx to Ox	$RL = 500\Omega$					
t PZH	Output Enable Time		1.5	6.2	1.5	5.8	ns
tPZL							
tphz	Output Disable Time		1.5	5.6	1.5	5.2	ns
tPLZ							

NOTES:

1. See test circuit and waveforms.

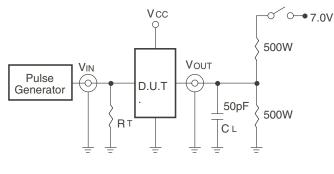
2. Minimum limits are guaranteed but not tested on Propagation Delays.



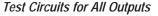
74FCT540AT/CT FASTCMOSOCTAL BUFFER/LINEDRIVER

INDUSTRIAL TEMPERATURE RANGE

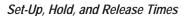
TEST CIRCUITS AND WAVEFORMS

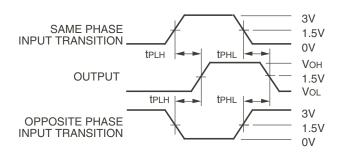


Octal Link



DATA 🔽 1.5V 0V INPUT tsu tн ЗV TIMING 1.5V 0V INPUT ASYNCHRONOUS CONTROL **t**REM PRESET ЗV 1.5V 0V CLEAR ETC. SYNCHRONOUS CONTROL ЗV PRESET 1.5V 0V CLEAR tsu тн **CLOCK ENABLE** ETC. Octal Link





Propagation Delay

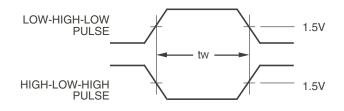
SWITCHPOSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

DEFINITIONS:

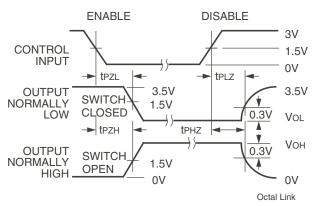
CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to Zout of the Pulse Generator.



Pulse Width

Octal Link



Enable and Disable Times

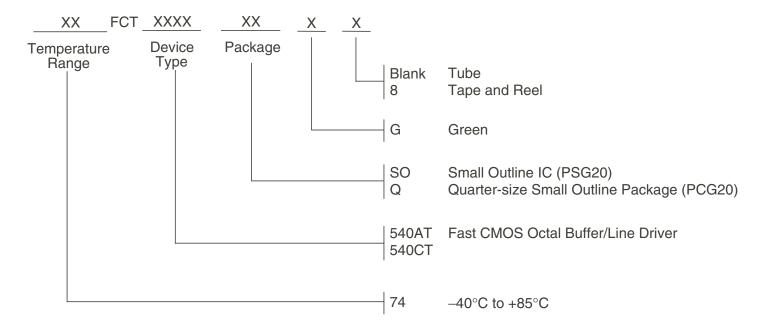
NOTES:

Octal Link

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.



ORDERING INFORMATION



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
А	74FCT540ATQG	PCG20	QSOP	Ι
	74FCT540ATQG8	PCG20	QSOP	Ι
	74FCT540ATSOG	PSG20	SOIC	Ι
	74FCT540ATSOG8	PSG20	SOIC	Ι
С	74FCT540CTQG	PCG20	QSOP	Ι
	74FCT540CTQG8	PCG20	QSOP	I
	74FCT540CTSOG	PSG20	SOIC	I
	74FCT540CTSOG8	PSG20	SOIC	I

Datasheet Document History

10/10/2009	Pg. 6	Updated the ordering information by removing the "IDT" notation and non RoHS part.
11/28/2016	Pgs. 1,2,6	Updated datasheet obsolete SSOP package and added Tube, Tape and Reel.
05/06/2019	Pgs. 2,6	Added table under pin configuration diagram with detailed package information and orderable part information table.
02/11/2020	Pgs. 1-7	Rebranded as Renesas datasheet.



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